LSIC2SD065C20A 650 V, 20 A SiC Schottky Barrier Diode









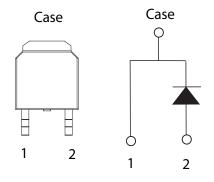
Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-252-2L (DPAK)



Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF**Halogen Free
- Littelfuse "Pb-free" logo = Pb-free lead plating

Maximum Ratings

| Characteristics | Symbol | Conditions | Value | Unit | | |
|--------------------------------------|------------------------|---|------------|--------------|--|--|
| Repetitive Peak Reverse Voltage | V _{RRM} | - | 650 | V | | |
| DC Blocking Voltage | V _R | T _J = 25 °C | 650 | V | | |
| Continuous Forward Current | T _c = 25 °C | T _c = 25 °C | 45 | V V A A W °C | | |
| | I _F | T _C = 135 °C | 20 | | | |
| Non-Repetitive Forward Surge Current | I _{FSM} | $T_{\rm C}$ = 25 °C, $T_{\rm P}$ = 10 ms, Half sine pulse | 90 | А | | |
| Power Dissipation | D | T _C = 25 °C | 135 | \\\ | | |
| | P _{Tot} | T _C = 110 °C | 60 | VV | | |
| Operating Junction Temperature | T _J | - | -55 to 175 | °C | | |
| Storage Temperature | T _{STG} | - | -55 to 150 | °C | | |
| Soldering Temperature (reflow MSL1) | T _{sold} | - | 260 | °C | | |

Electrical Characteristics

| | | | Value | | | |
|--|----------------|--|-------|------|------|------|
| Characteristics | Symbol | Conditions | Min. | Тур. | Max. | Unit |
| Forward Voltage $V_{\scriptscriptstyle F}$ | \ / | I _F = 20 A, T _J = 25 °C | - | 1.5 | 1.8 | V |
| | V _F | I _F = 20 A, T _J = 175 °C | - | 1.85 | - | |
| Reverse Current I _R | _ | $V_{R} = 650 \text{V}, T_{J} = 25 ^{\circ}\text{C}$ | - | <1 | 50 | μΑ |
| | I _R | $V_{R} = 650 \text{V}, T_{J} = 175 ^{\circ}\text{C}$ | - | 60 | - | |
| Total Capacitance C | | V _R = 1 V, f = 1 MHz | - | 960 | - | |
| | С | $V_{R} = 200 \text{V}, f = 1 \text{MHz}$ | - | 120 | - | pF |
| | | $V_{R} = 400 \text{V}, f = 1 \text{MHz}$ | - | 86 | - | |
| Total Capacitive Charge | Q _c | $V_R = 400 \text{ V}, \ Q_C = \int\limits_0^{V_R} C(V) dV$ | - | 63 | - | nC |

| Thermal Characteristics | | | | | | |
|-------------------------|------------------|-------|------|--|--|--|
| Characteristics | Symbol | Value | Unit | | | |
| Thermal Resistance | R _{eJC} | 1.1 | °C/W | | | |

Figure 1: Typical Foward Characteristics

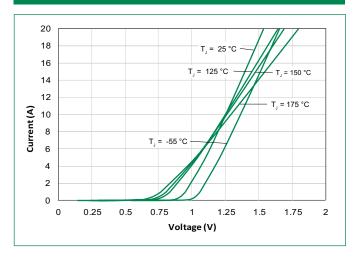


Figure 2: Typical Reverse Characteristics

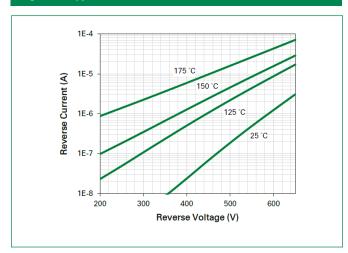




Figure 3: Power Derating

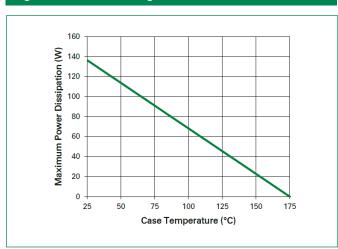


Figure 4: Current Derating

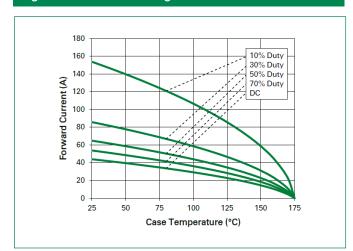


Figure 5: Capacitance vs. Reverse Voltage

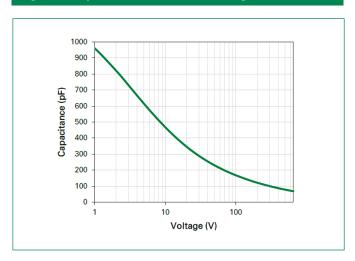


Figure 6: Capacitive Charge vs. Reverse Voltage

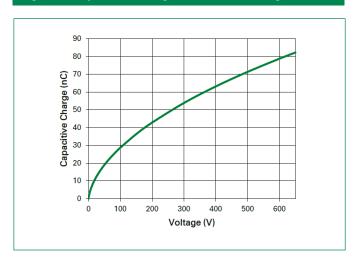


Figure 7: Stored Energy vs. Reverse Voltage

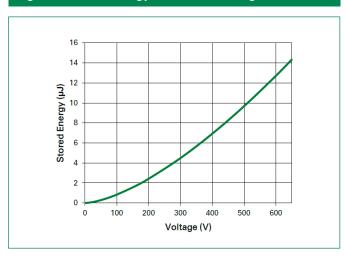
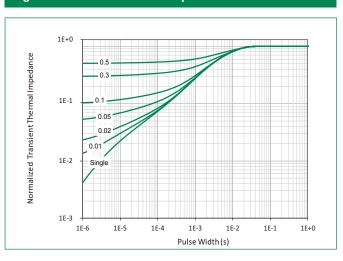
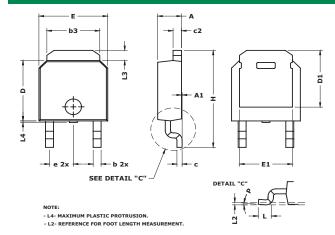


Figure 8: Transient Thermal Impedance

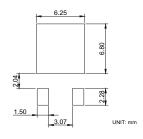




Dimensions TO-252-2L (DPAK)

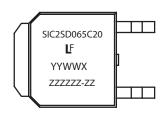


Recommended Solder Pattern Layout



| Cumphal | | Inches | | N | Millimeters | | | |
|---------|-----------|--------|-------|------|-------------|-------|--|--|
| Symbol | Min | Nom | Max | Min | Nom | Max | | |
| Α | 0.085 | 0.090 | 0.095 | 2.16 | 2.29 | 2.41 | | |
| A1 | 0 | 0.003 | 0.005 | 0 | 0.08 | 0.13 | | |
| b | 0.025 | 0.030 | 0.035 | 0.64 | 0.76 | 0.89 | | |
| b3 | 0.195 | 0.200 | 0.215 | 4.95 | 5.08 | 5.46 | | |
| С | 0.018 | 0.020 | 0.024 | 0.46 | 0.51 | 0.61 | | |
| C2 | 0.018 | 0.032 | 0.035 | 0.46 | 0.81 | 0.89 | | |
| D | 0.235 | 0.240 | 0.245 | 5.97 | 6.10 | 6.22 | | |
| D1 | 0.205 | - | - | 5.21 | - | - | | |
| Е | 0.250 | 0.260 | 0.265 | 6.35 | 6.60 | 6.73 | | |
| E1 | 0.170 | - | - | 4.32 | - | - | | |
| е | 0.090 BSC | | | | 2.29 BS | С | | |
| Н | 0.370 | 0.387 | 0.410 | 9.40 | 9.83 | 10.41 | | |
| L | 0.040 | 0.045 | 0.050 | 1.02 | 1.14 | 1.27 | | |
| L2 | 0.010 BSC | | | | 0.25 BS | 0.76 | | |
| L3 | 0.035 | - | 0.050 | 0.89 | - | 1.27 | | |
| L4 | 0 | - | 0.006 | 0 | - | 0.15 | | |
| Р | 0° | - | 8° | 0° | - | 8° | | |

Part Numbering and Marking System



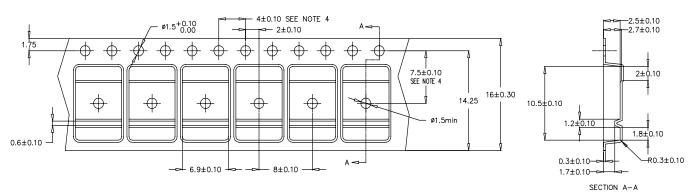
| SIC | = SiC Diode |
|-----------|--------------------------|
| 2 | = Gen2 |
| SD | = Schottky Diode |
| 065 | = Voltage Rating (650 V) |
| С | = TO-252-2L (DPAK) |
| 20 | = Current Rating (20 A) |
| YY | = Year |
| WW | = Week |
| X | = Special code |
| ZZZZZZ-ZZ | Z = Lot Number |

Packing Options

| Part Number | Part Number Marking | | M.O.Q |
|----------------|---------------------|---------------|-------|
| LSIC2SD065C20A | SIC2SD065C20 | Tape and Reel | 2500 |

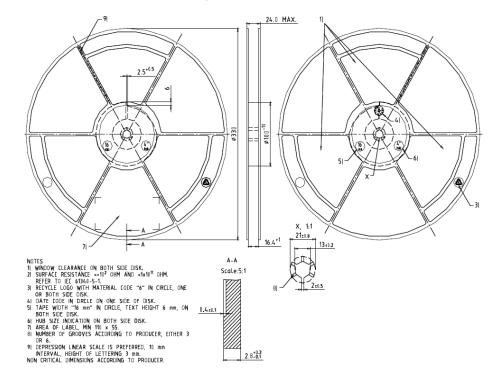


Carrier Tape & Reel Specification TO-252-2L (DPAK)



- Material: Black Conductive Polysterene

- 1. Material: Black Conductive Polysterene
 2. 10 sprocket hole pitch cumulative tolerance ± 0.20
 3. Camber not to exceed 1 mm in 100 mm.
 4. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.
 5. Device orientation: TRL (leads perpendicular to the sprocket)
- 6. General tolerance is \pm 0.10 mm unless otherwise specified.



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